**Product data sheet** 

# 1. General description

High voltage, high speed, planar passivated NPN power switching transistor in a SOT54 (TO-92) plastic package.

### 2. Features and benefits

- Fast switching
- High typical DC current gain
- High voltage capability of 700 V
- Very low switching and conduction losses

# 3. Applications

- Compact fluorescent lamps (CFL)
- Low power electronic lighting ballasts
- Off-line self-oscillating power supplies (SOPS) for battery charging

### 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
I <sub>C</sub>	collector current	DC		-	-	1.5	Α
P <sub>tot</sub>	total power dissipation	T <sub>lead</sub> ≤ 25 °C; <u>Fig. 1</u>		-	-	2.1	W
V <sub>CESM</sub>	collector-emitter peak voltage	V <sub>BE</sub> = 0 V		-	-	700	V
Static characteristics							
h <sub>FE</sub>	DC current gain	$I_C$ = 0.5 A; $V_{CE}$ = 2 V; $T_{lead}$ = 25 °C		8	17	25	





**NPN** power transistor

# 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base		C
2	С	collector		В
3	Е	emitter		, h
			321	E sym123
			TO-92 (SOT54)	

# 6. Ordering information

Table 3. Ordering information

Type number	Package						
	Name	Description	Version				
PHE13003C	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54				

# 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CESM</sub>	collector-emitter peak voltage	V <sub>BE</sub> = 0 V	-	700	V
V <sub>CBO</sub>	collector-base voltage	I <sub>E</sub> = 0 A	-	700	V
V <sub>CEO</sub>	collector-emitter voltage	I <sub>B</sub> = 0 A	-	400	V
I <sub>C</sub>	collector current	DC	-	1.5	Α
I <sub>CM</sub>	peak collector current		-	3	Α
I <sub>B</sub>	base current	DC	-	0.75	Α
I <sub>BM</sub>	peak base current		-	1.5	Α
P <sub>tot</sub>	total power dissipation	T <sub>lead</sub> ≤ 25 °C; <u>Fig. 1</u>	-	2.1	W
T <sub>stg</sub>	storage temperature		-65	150	°C
Tj	junction temperature		-	150	°C
V <sub>EBO</sub>	emitter-base voltage	I <sub>C</sub> = 0 A; I(Emitter) = 10 mA	-	9	V

#### **NPN** power transistor

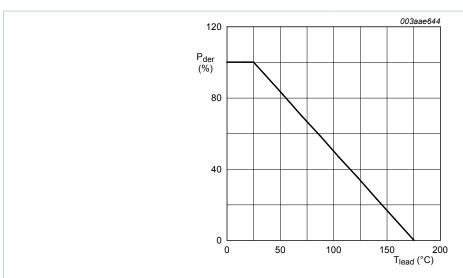


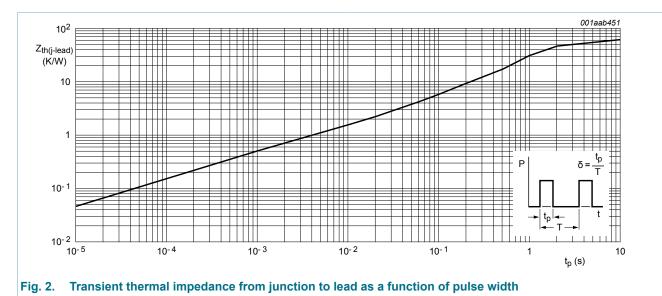
Fig. 1. Normalized total power dissipation as a function of lead temperature

$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}\text{C})}} \times 100 \,\%$$

## 8. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R <sub>th(j-lead)</sub>	thermal resistance from junction to lead	Fig. 2	-	-	60	K/W
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air; printed circuit board mounted; lead length = 4 mm	-	150	-	K/W



PHE13003C

**NPN** power transistor

# 9. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Dynamic cl	naracteristics					
t <sub>on</sub>	turn-on time	I <sub>C</sub> = 1 A; I <sub>Bon</sub> = 0.2 A; I <sub>Boff</sub> = -0.2 A;	-	-	1	μs
t <sub>s</sub> storage time	storage time	$R_L = 75 \Omega$ ; $T_{lead} = 25 ^{\circ}C$ ; resistive load; Fig. 5; Fig. 6	-	-	4	μs
		$I_C$ = 1 A; $I_{Bon}$ = 0.2 A; $V_{BB}$ = -5 V; $L_B$ = 1 $\mu$ H; $T_{lead}$ = 25 °C; inductive load; Fig. 7; Fig. 8	-	0.8	-	μs
t <sub>f</sub>	fall time	$I_C$ = 1 A; $I_{Bon}$ = 0.2 A; $I_{Boff}$ = -0.2 A; $R_L$ = 75 $\Omega$ ; $T_{lead}$ = 25 °C; resistive load; <u>Fig. 5</u> ; <u>Fig. 6</u>	-	-	0.7	μs
		$I_C$ = 0.5 A; $I_{Bon}$ = 0.1 A; $V_{BB}$ = -5 V; $L_B$ = 1 $\mu$ H; $T_{lead}$ = 25 °C; inductive load; Fig. 7; Fig. 8	-	0.1	-	μs
Static char	acteristics					
I <sub>CES</sub>	collector-emitter cut-off current	V <sub>BE</sub> = 0 V; V <sub>CE</sub> = 700 V; T <sub>j</sub> = 125 °C	-	-	5	mA
		V <sub>BE</sub> = 0 V; V <sub>CE</sub> = 700 V; T <sub>j</sub> = 25 °C	-	-	1	mA
I <sub>CEO</sub>	collector-emitter cut-off current	V <sub>CE</sub> = 400 V; I <sub>B</sub> = 0 A; T <sub>lead</sub> = 25 °C	-	-	0.1	mA
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 9 V; I <sub>C</sub> = 0 A; T <sub>lead</sub> = 25 °C	-	-	1	mA
V <sub>CEOsus</sub>	collector-emitter sustaining voltage	$I_B = 0 \text{ A}; I_C = 1 \text{ mA}; L_C = 25 \text{ mH};$ $T_{lead} = 25 \text{ °C}; \underline{\text{Fig. 3}}; \underline{\text{Fig. 4}}$	400	-	-	V
V <sub>CEsat</sub>	collector-emitter	I <sub>C</sub> = 0.5 A; I <sub>B</sub> = 0.1 A; T <sub>lead</sub> = 25 °C	-	-	0.5	V
	saturation voltage	I <sub>C</sub> = 1 A; I <sub>B</sub> = 0.25 A; T <sub>lead</sub> = 25 °C	-	-	1	V
		I <sub>C</sub> = 1.5 A; I <sub>B</sub> = 0.5 A; T <sub>lead</sub> = 25 °C	-	-	1.5	V
V <sub>BEsat</sub>	base-emitter saturation	I <sub>C</sub> = 0.5 A; I <sub>B</sub> = 0.1 A; T <sub>lead</sub> = 25 °C	-	-	1	V
	voltage	I <sub>C</sub> = 1 A; I <sub>B</sub> = 0.25 A; T <sub>lead</sub> = 25 °C	-	-	1.2	V
h <sub>FE</sub>	DC current gain	I <sub>C</sub> = 0.5 A; V <sub>CE</sub> = 2 V; T <sub>lead</sub> = 25 °C	8	17	25	
		I <sub>C</sub> = 1 A; V <sub>CE</sub> = 2 V; T <sub>lead</sub> = 25 °C	5	9	15	

#### **NPN** power transistor

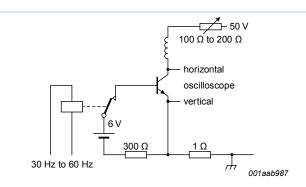


Fig. 3. Test circuit for collector-emitter sustaining voltage

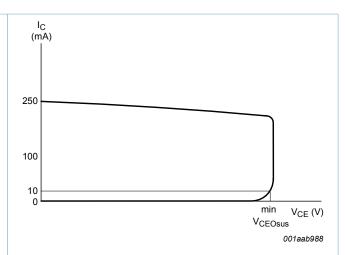


Fig. 4. Oscilloscope display for collector-emitter sustaining voltage test waveform

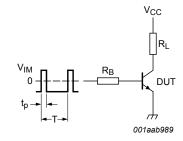


Fig. 5. Test circuit for resistive load switching

 $V_{IM} = -6$  to +8 V;  $V_{CC} = 250$  V;  $t_p = 20$   $\mu$ s;  $\delta = \frac{t_p}{T} = 0.01$   $R_B$  and  $R_L$  calculated from  $I_{Con}$  and  $I_{Bon}$  requirements.

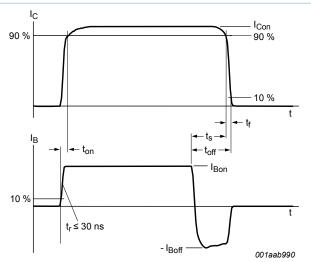
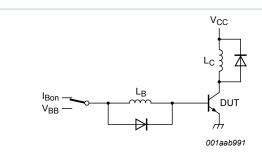


Fig. 6. Switching times waveforms for resistive load

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### Fig. 7. Test circuit for inductive load switching

$$V_{CC} = 300 \ V; V_{BB} = -5 \ V; L_{C} = 200 \ \mu H; L_{B} = 1 \ \mu H$$

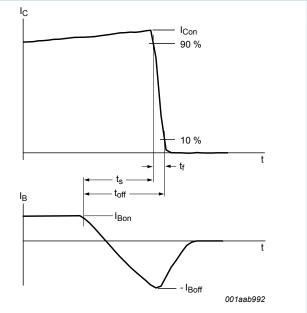


Fig. 8. Switching times waveforms for inductive load

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# 10. Package outline

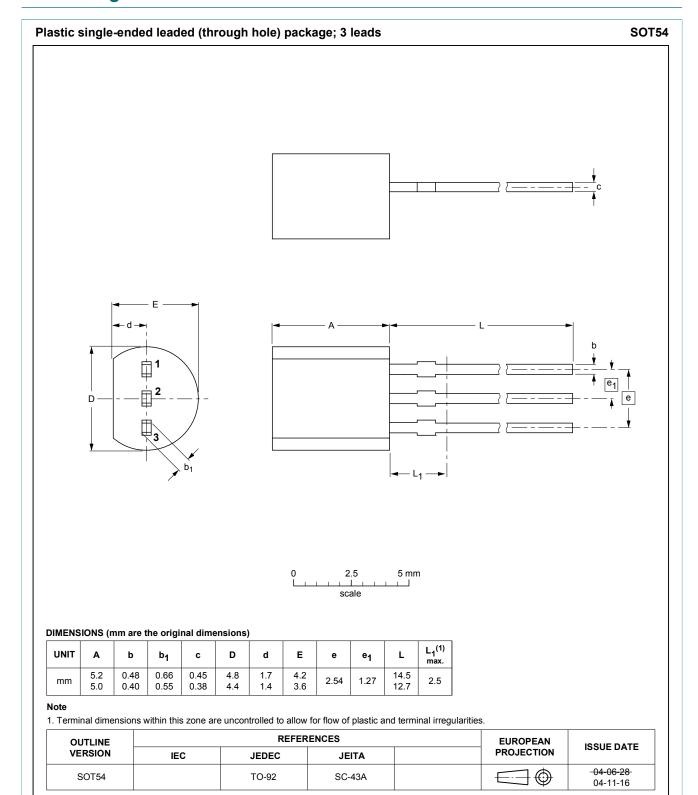


Fig. 9. Package outline TO-92 (SOT54)

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### **NPN** power transistor

## 12. Contents

1	General description	1
2	Features and benefits	1
3	Applications	1
4	Quick reference data	1
5	Pinning information	2
6	Ordering information	2
7	Limiting values	2
8	Thermal characteristics	3
9	Characteristics	4
10	Package outline	7
11	Legal information	8
11.1	Data sheet status	
11.2	Definitions	8
11.3	Disclaimers	8
11.4	Trademarks	9

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